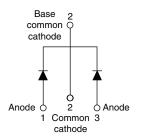


# VS-16CTQ...PbF Series, VS-16CTQ...-N3 Series

Vishay Semiconductors

## Schottky Rectifier, 2 x 8 A



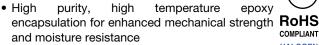


TO-220AB
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PRODUCT SUMMARY					
Package	TO-220AB				
I <sub>F(AV)</sub>	2 x 8 A				
$V_{R}$	60 V, 80 V, 100 V				
V <sub>F</sub> at I <sub>F</sub>	0.58 V				
I <sub>RM</sub> max.	7 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	7.5 mJ				

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long FREE term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

### **DESCRIPTION**

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL CHARACTERISTICS VALUES UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	16	А			
$V_{RRM}$		60 to 100	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	А			
V <sub>F</sub>	8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.58	V			
$T_J$	Range	- 55 to 175	°C			

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS- 16CTQ060PbF	VS- 16CTQ060-N3	VS- 16CTQ080PbF	VS- 16CTQ080-N3	VS- 16CTQ100PbF	VS- 16CTQ100-N3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>							
Maximum working peak reverse voltage	V <sub>RWM</sub>	60	60	80	80	100	100	V

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	per leg		I <sub>F(A\0)</sub> 50 % duty cycle at T <sub>C</sub> = 148 °C, rectangular waveform		8	Α	
See fig. 5	per device	I <sub>F(AV)</sub>	50 % duty cycle at 1 <sub>C</sub> = 146 °C	16	^		
Maximum peak one cycle non-repetitive		I	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		850	A	
surge current per leg See fig. 7	IFSM		10 ms sine or 6 ms rect. pulse			A	
Non-repetitive avalanche ene	rgy per leg	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 0.50  \text{A},  L = 60  \text{C}$	) mH	7.50	mJ	



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ABSOLUTE MAXIMUM RATINGS							
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical	0.50	Α			

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop per leg See fig. 1		8 A	T <sub>.1</sub> = 25 °C	0.72	V	
	V <sub>FM</sub> <sup>(1)</sup>	16 A	1j=25 C	0.88		
	V <sub>FM</sub> (1)	8 A	T 105 °C	0.58		
		16 A	T <sub>J</sub> = 125 °C	0.69		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	M and AM	0.55	mA	
See fig. 2	IRM (1)	T <sub>J</sub> = 125 °C	V <sub>R</sub> = rated V <sub>R</sub>	7.0		
Threshold voltage	V <sub>F(TO)</sub>	T T maximum		0.415	V	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		11.07	mΩ	
Maximum junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		500	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/μs	

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C			
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	3.25	°C/W			
Maximum thermal resistance junction to case per package	R <sub>thJC</sub>	DC operation	1.63	O/VV			
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50				
Approximate weight			2	g			
Approximate weight			0.07	OZ.			
Mounting torque minimum			6 (5)	kgf ⋅ cm			
Mounting torque maximum			12 (10)	(lbf · in)			
			16CT	Q060			
Marking device		Case style TO-220AB	16CTQ080				
			16CTQ100				

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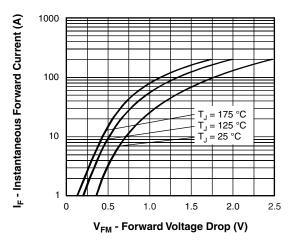


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

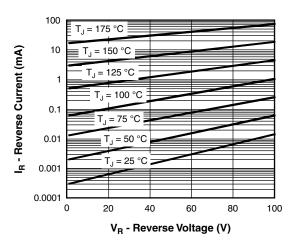


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

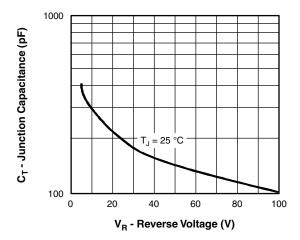


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

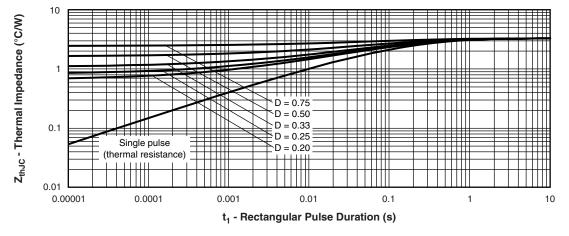


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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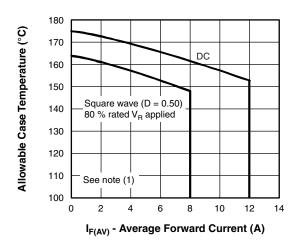


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

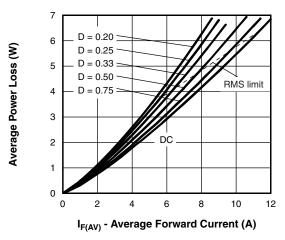


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

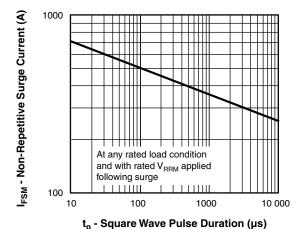


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

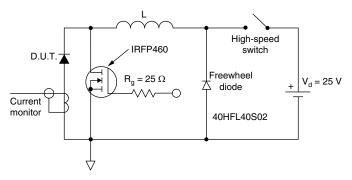


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

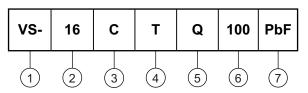
 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub> applied

# VS-16CTQ...PbF Series, VS-16CTQ...-N3 Series

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#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (16 = 16 A)

3 - Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

060 = 60 V 080 = 80 V

6 - Voltage rating

100 = 100 V

7 - Environmental digit

- PbF = Lead (Pb)-free and RoHS compliant
- -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-16CTQ060PbF	50	1000	Antistatic plastic tube				
VS-16CTQ060-N3	50	1000	Antistatic plastic tube				
VS-16CTQ080PbF	50	1000	Antistatic plastic tube				
VS-16CTQ080-N3	50	1000	Antistatic plastic tube				
VS-16CTQ100PbF	50	1000	Antistatic plastic tube				
VS-16CTQ100-N3	50	1000	Antistatic plastic tube				

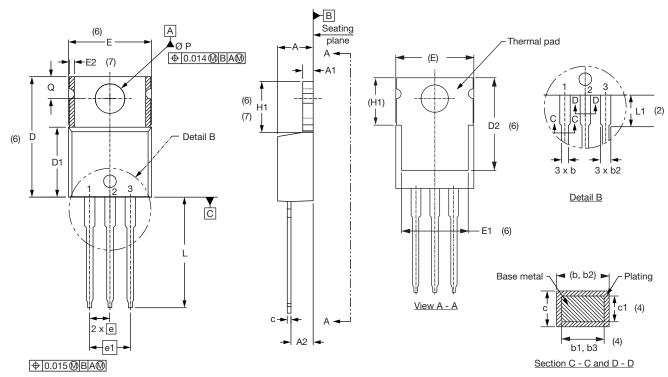
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Pod and in information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95279			



## Vishay Semiconductors

## **TO-220AB**

#### **DIMENSIONS** in millimeters and inches



## Lead assignments

#### **Diodes**

- 1. Anode/open
- 2. Cathode
- 3. Anode

#### Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIMETERS INCHES		NOTES		
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	
		•	•	•	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



## **Legal Disclaimer Notice**

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